BEST PAPER AWARD

The Best Paper Award Committee of the 35th European Symposium on Reliability of Electron Devices, Failure Physics and Analysis, ESREF 2024, Parma, Italy, September 23-26

presents the Best Paper Award to the paper entitled

OFF-state Breakdown and Threshold Voltage Stability of Vertical GaN-on-Si Trench MOSFETs

Authored by

Manuel Fregolent, Francesco Bergamin, Davide Favero, Carlo De Santi, Christian Huber, Gaudenzio Meneghesso, Enrico Zanoni, and Matteo Meneghini

Paolo Cova ESREF 2024 General Chair





François Marc Best-Paper Award Chair